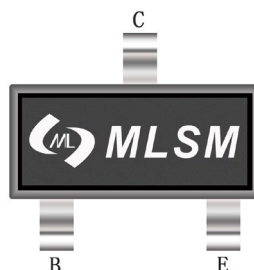
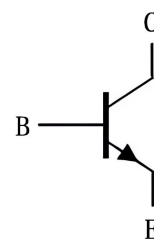


Features

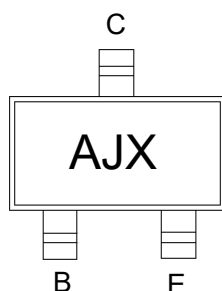
- Low $V_{CE(sat)}$
- High BV_{CEO}
- Complements the 2SB1198



SOT-23 top view



Schematic diagram



Marking and pin assignment

X:Rank



Halogen-Free

Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	80	V
V_{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	500	mA
P_C	Collector Power Dissipation	200	mW
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
2SD1782	SOT-23	AJQ/AJR	3,000	45,000	180,000	7"reel

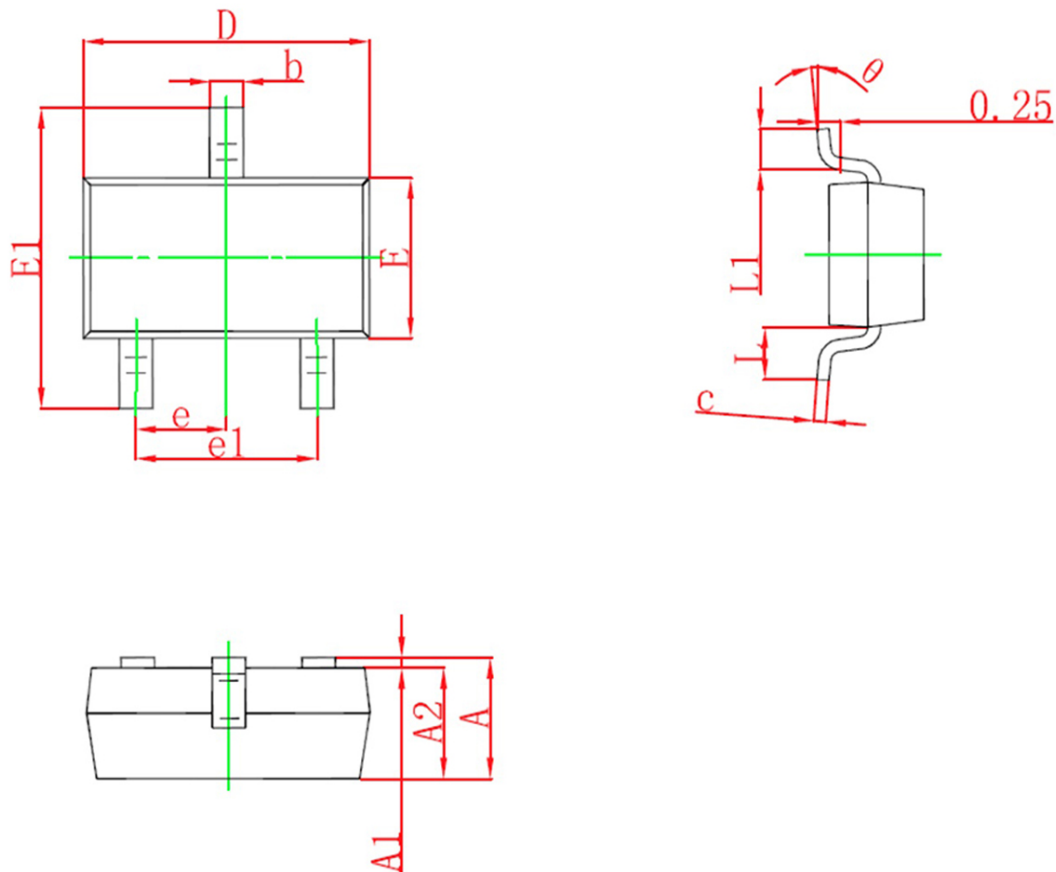
Electrical Characteristics (Ta=25°C unless otherwise specified)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{(BR)CBO}$	Collector-base breakdown voltage	$I_C=50\mu A, I_E=0$	80	--	--	V
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C=2mA, I_B=0$	80	--	--	V
$V_{(BR)EBO}$	Emitter-base breakdown voltage	$I_E=50\mu A, I_C=0$	5	--	--	V
I_{CBO}	Collector cut-off current	$V_{CB}=50V, I_E=0$	--	--	0.5	μA
I_{EBO}	Emitter cut-off current	$V_{EB}=4V, I_C=0$	--	--	0.5	μA
$H_{FE(1)}$	DC current gain	$V_{CE}=3V, I_C=100mA$	120	--	390	
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_C=500mA, I_B=50mA$	--	--	0.5	V
C_{ob}	Collector output capacitance	$V_{CB}=10V, I_E=0, f=1MHz$	--	7.5	--	pF
f_T	Transition frequency	$V_{CE}=10V, I_C=50mA, f=100MHz$	--	120	--	MHz

Classification of hFE

Rank	Q	R
Marking	AJQ	AJR
Range	120-270	180-390

SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°